TOSHIBA Photocoupler GaAs Ired & Photo-Transistor

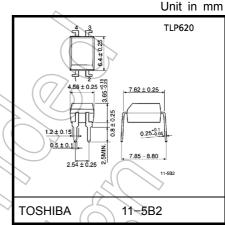
# TLP620, TLP620-2, TLP620-4

Programmable Controllers
AC / DC-Input Module
Telecommunication

The TOSHIBA TLP620, -2 and -4 consists of a photo–transistor optically coupled to two gallium arsenide infrared emitting diode connected in inverse parallel.

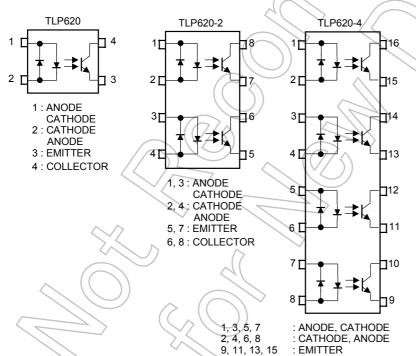
The TLP620–2 offers two isolated channels in an eight lead plastic DIP, while the TLP620–4 provides four isolated channels in a sixteen plastic DIP

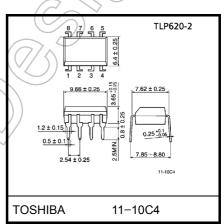
- Collector-emitter voltage: 55V (min.)
- Current transfer ratio: 50% (min.) Rank GB: 100% (min.)



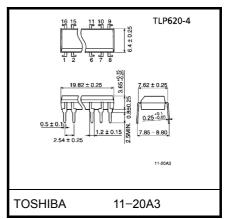
Weight: 0,26 g (typ.)

### Pin Configurations (top view)





Weight: 0.54 g (typ.)



Weight: 1.1 g (typ.)

10, 12, 14, 16 : COLLECTOR

	Made In Japan	Made In Thailand		
UL recognized	E67349	*1	E152349	*1
BSI approved	7426, 7427	*2	7426, 7427	*2

\*1 UL1577

\*2 BS EN60065: 2002, BS EN60950-1: 2002

• Isolation voltage: 5000V<sub>rms</sub> (min.)

• Option (D4) type

VDE approved: DIN EN 60747-5-2, certificate no.40009302 Maximum operating insulation voltage: 890VPK Highest permissible over voltage: 8000VPK

(Note) When an EN 60747-5-2 approved type is needed, please designate the "Option(D4)".

• Creepage distance: 6.4mm (min.) Clearance: 6.4mm (min.)

Insulation thickness: 0.4mm (min.)

#### **Absolute Maximum Ratings (Ta = 25°C)**

Characteristic		Symbol	Rat	ing TLP620-2	Unit
			TLP620	TLP620-4	
	Forward current	IF (RMS)	60	50	mA
	Forward current derating	ΔI <sub>F</sub> / °C	–0.7 (Ta ≥ 39°C)	–0.5 (Ta ≥ 25°C)	mA / °C
Ω	Pulse forward current	IFP	1 (100µs pulse, 100pps)		Α
LED	Power dissipation (1 circuit)	PD	100	70	mW
	Power dissipation derating	ΔP <sub>D</sub> /°C	-1.0	-0.7	mW / °C
	Junction temperature	(Ij))	12	25	°C
	Collector–emitter voltage	VCEO	5	V	
	Emitter-collector voltage	) V <sub>ECO</sub>		V	
Ä	Collector current	, lc \	I <sub>C</sub> 50		mA
Detector	Collector power dissipation (1 circuit)	Pc	150	100	mW
	Collector power dissipation derating (1 circuit) (Ta ≥ 25°C)	ΔP <sub>C</sub> / °C	-1.5	-1.0	mW / °C
	Junction temperature	<b>/</b> ₹j	12	25	°C
Stor	age temperature range	T <sub>stg</sub>	<b>−55~125</b>		°C
Оре	Operating temperature range		<b>−55~100</b>		°C
Lea	ad soldering temperature T <sub>sold</sub>		260 (10s)		°C
Tota	Total package power dissipation		250	150	mW
Total package power dissipation derating (Ta ≥ 25°C, 1 circuit)		ΔP <sub>T</sub> / °C	-2.5	-1.5	mW / °C
Isolation voltage		BVS	5000 (AC, 1 min., RH ≤ 60%)		V <sub>rms</sub>

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).



#### **Recommended Operating Conditions**

Characteristic	Symbol	Min.	Тур.	Max.	Unit
Supply voltage	$V_{CC}$	_	5	24	V
Forward current	I <sub>F (RMS)</sub>	_	16	20	mA
Collector current	IC	_	1	10	mA
Operating temperature	T <sub>opr</sub>	-25	_	85	°C

Note: Recommended operating conditions are given as a design guideline to obtain expected performance of the device. Additionally, each item is an independent guideline respectively. In developing designs using this product, please confirm specified characteristics shown in this document.

## Individual Electrical Characteristics (Ta = 25°C)

	Characteristic	Symbol	Test Condition	Min.	Тур.	Max.	Unit
	Forward voltage	V <sub>F</sub>	I <sub>F</sub> = ±10mA	1.0	1.15	1.3	V
LED	Forward current	lF	V <sub>F</sub> = ±0.7V	7	2.5	20	μΑ
	Capacitance	C <sub>T</sub>	V = 0, f = 1MHz		60/	_	pF
	Collector–emitter breakdown voltage	V (BR) CEO	I <sub>C</sub> ≠ 0.5mA	55	_		V
ctor	Emitter–collector breakdown voltage	V (BR) ECO	IE = 0.1mA	7	-		V
Detector	Collector dark current	1	V <sub>CE</sub> = 24V	_	10	100	nA
	Collector dark current	ICEO	V <sub>CE</sub> = 24V, Ta = 85°C	1	2	50	μA
	Capacitance (collector to emitter)	C <sub>CE</sub>	V <sub>CE</sub> = 0, f = 1MHz	_	10	_	pF

## Coupled Electrical Characteristics (Ta = 25°C)

Characteristic	Symbol	Test Condition	MIn.	Тур.	Max.	Unit
Current transfer ratio	10.115	I <sub>C</sub> / I <sub>F</sub> = ±5mA, V <sub>CE</sub> = 5V	50	_	600	%
	IC / IF		100	_	600	%
Saturated CTR	lo /l= \alpha	IF = ±1mA, V <sub>CE</sub> = 0.4V	_	60	-	%
	IC / IF (sat) Rank GB	30	1	ı	/0	
		I <sub>C</sub> = 2.4mA, I <sub>F</sub> = ±8mA	_	_	0.4	
Collector–emitter saturation voltage	VCE (sat)	VCE (sat) $I_C = 0.2 \text{ mA}, I_F = \pm 1 \text{ mA}$ Rank GB	_	0.2	_	V
			_	_	0.4	
Off-state collector current	IC (off)	$V_F = \pm 0.7V$ , $V_{CE} = 24V$	_	1	10	μΑ
CTR symmetry	Ic (ratio)	$I_{C} (I_{F} = -5mA) / I_{C} (I_{F} = +5mA)$	0.33	1	3	_



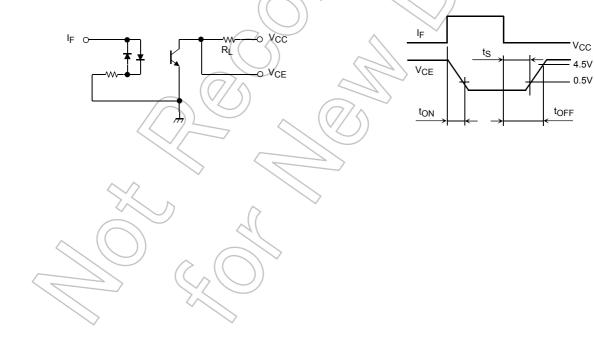
# Isolation Characteristics (Ta = 25°C)

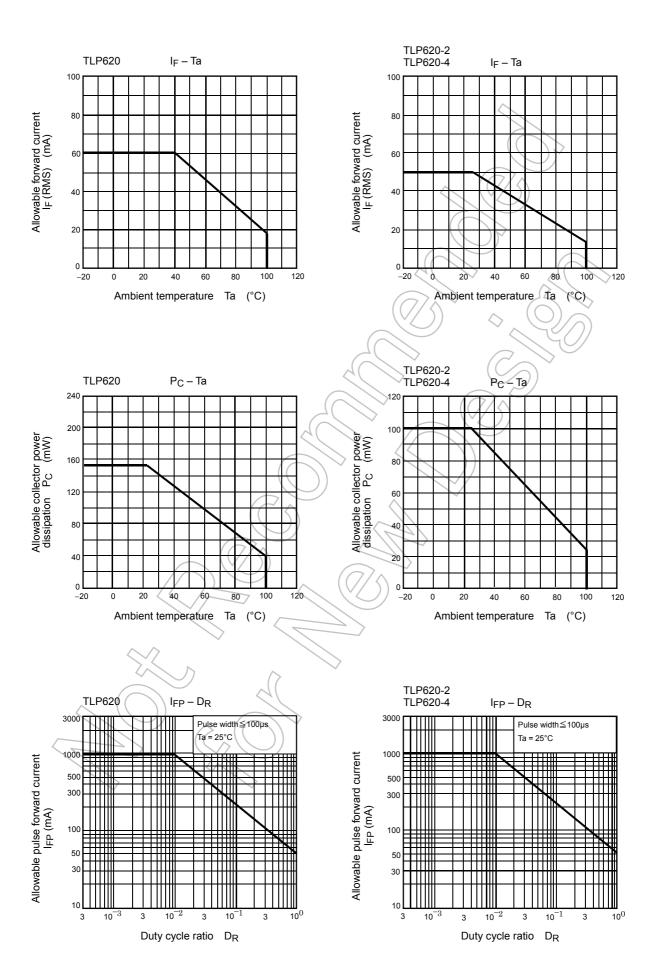
Characteristic	Symbol	Test Condition	Min.	Тур.	Max.	Unit
Capacitance input to output	CS	V <sub>S</sub> = 0, f = 1MHz	_	0.8	_	pF
Isolation resistance	R <sub>S</sub>	V <sub>S</sub> = 500V	1×10 <sup>12</sup>	10 <sup>14</sup>	_	Ω
Isolation voltage		AC, 1 minute	5000	_	_	V
	$BV_S$	AC, 1 second, in oil	((-)	10000	_	V <sub>rms</sub>
		DC, 1 minute, in oil	7	10000	_	V <sub>dc</sub>

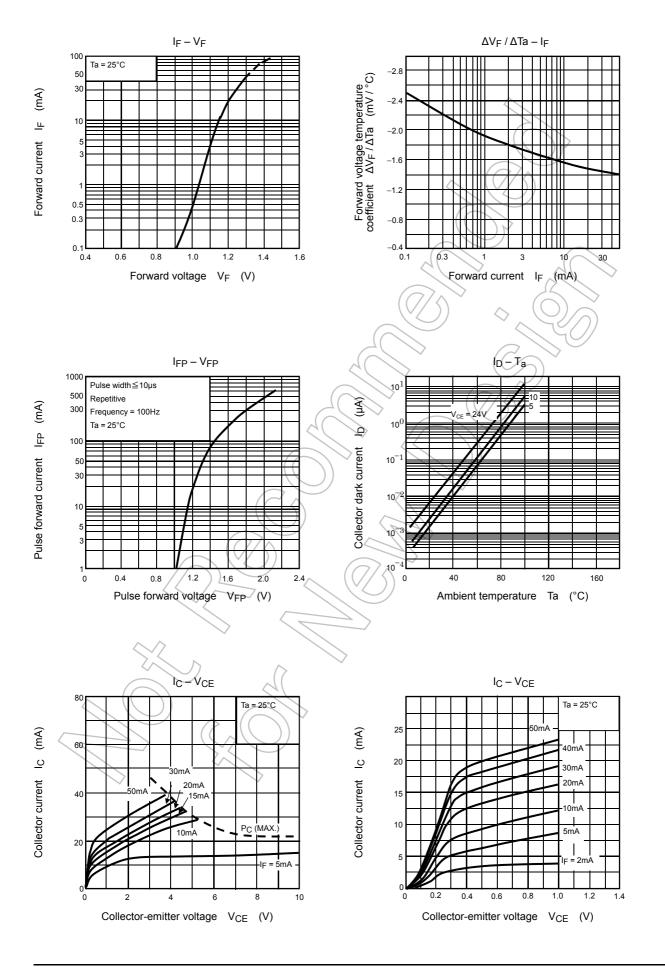
# **Switching Characteristics (Ta = 25°C)**

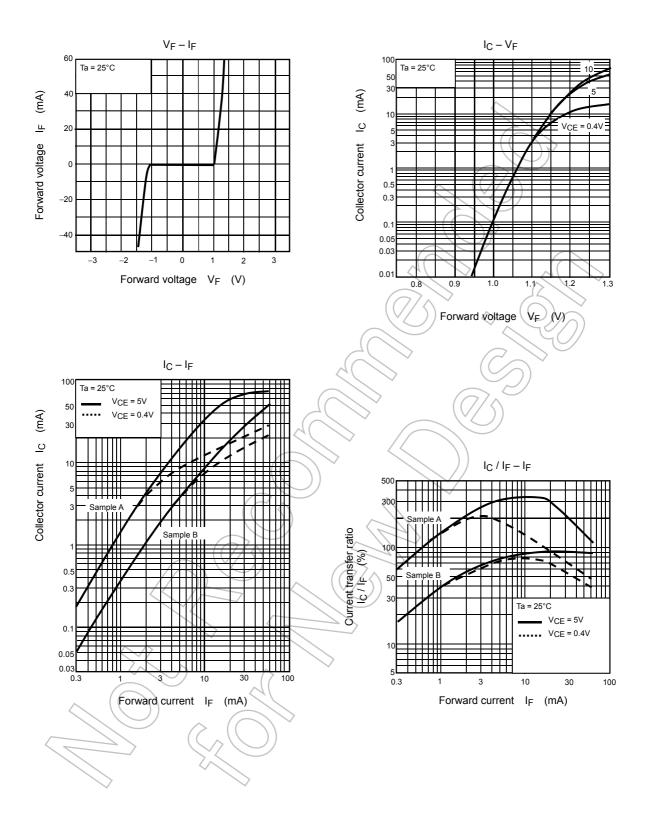
Characteristic	Symbol	Test Condition	Min.	Тур.	Max.	Unit
Rise time	t <sub>r</sub>	40	_	2	\ <u></u>	
Fall time	t <sub>f</sub>	V <sub>CC</sub> = 10V	- /	3	_	
Turn-on time	t <sub>on</sub>	I <sub>C</sub> = 2mA R <sub>L</sub> = 100Ω	-((	)3	_	μs
Turn-off time	t <sub>off</sub>	· ·	(+)	(3)	/ —	
Turn-on time	t <sub>ON</sub>		7 -	> 2	_	
Storage time	ts	$R_L = 1.9k\Omega$ (Fig.1) $V_{CC} = 5V$ , $I_F = \pm 16mA$	(9)	15	_	μs
Turn-off time	toff			25	_	

Fig. 1 Switching time test circuit

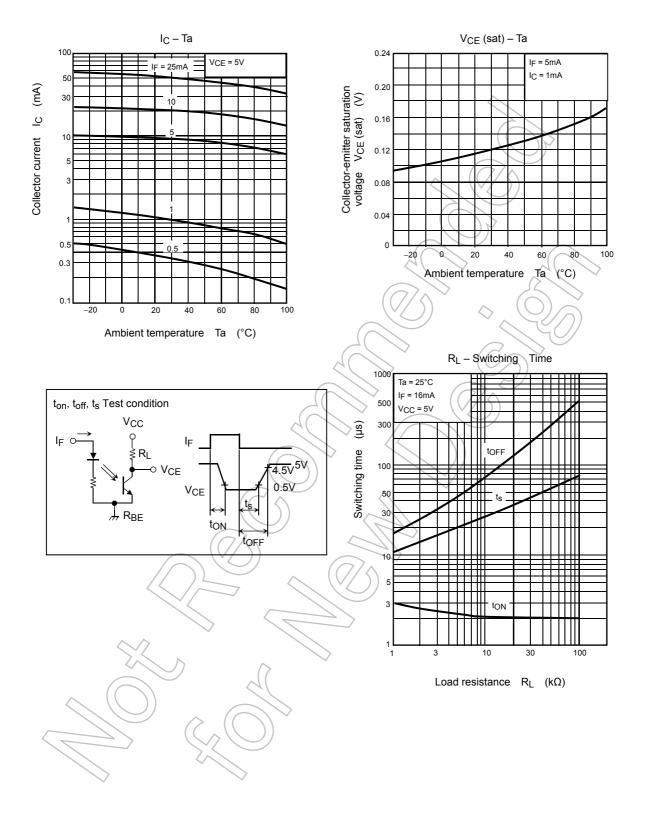








7



#### **RESTRICTIONS ON PRODUCT USE**

- Toshiba Corporation, and its subsidiaries and affiliates (collectively "TOSHIBA"), reserve the right to make changes to the information in this document, and related hardware, software and systems (collectively "Product") without notice.
- This document and any information herein may not be reproduced without prior written permission from TOSHIBA. Even with TOSHIBA's written permission, reproduction is permissible only if reproduction is without alteration/omission.
- Though TOSHIBA works continually to improve Product's quality and reliability, Product can malfunction or fail. Customers are responsible for complying with safety standards and for providing adequate designs and safeguards for their hardware, software and systems which minimize risk and avoid situations in which a malfunction or failure of Product could cause loss of human life, bodily injury or damage to property, including data loss or corruption. Before customers use the Product, create designs including the Product, or incorporate the Product into their own applications, customers must also refer to and comply with (a) the latest versions of all relevant TOSHIBA information, including without limitation, this document, the specifications, the data sheets and application notes for Product and the precautions and conditions set forth in the "TOSHIBA Semiconductor Reliability Handbook" and (b) the instructions for the application with which the Product will be used with or for. Customers are solely responsible for all aspects of their own product design or applications, including but not limited to (a) determining the appropriateness of the use of this Product in such design or applications; (b) evaluating and determining the applicability of any information contained in this document, or in charts, diagrams, programs, algorithms, sample application circuits, or any other referenced documents; and (c) validating all operating parameters for such designs and applications. TOSHIBA ASSUMES NO LIABILITY FOR CUSTOMERS' PRODUCT DESIGN OR APPLICATIONS.
- PRODUCT IS NEITHER INTENDED NOR WARRANTED FOR USE IN EQUIPMENTS OR SYSTEMS THAT REQUIRE
  EXTRAORDINARILY HIGH LEVELS OF QUALITY AND/OR RELIABILITY, AND/OR A MALFUNCTION OR FAILURE OF WHICH
  MAY CAUSE LOSS OF HUMAN LIFE, BODILY INJURY, SERIOUS PROPERTY DAMAGE AND/OR SERIOUS PUBLIC IMPACT
  ("UNINTENDED USE"). Except for specific applications as expressly stated in this document, Unintended Use includes, without
  limitation, equipment used in nuclear facilities, equipment used in the aerospace industry, medical equipment, equipment used for
  automobiles, trains, ships and other transportation, traffic signaling equipment, equipment used to control compustions or explosions,
  safety devices, elevators and escalators, devices related to electric power, and equipment used in finance-related fields. IF YOU USE
  PRODUCT FOR UNINTENDED USE, TOSHIBA ASSUMES NO LIABILITY FOR PRODUCT. For details, please contact your
  TOSHIBA sales representative.
- . Do not disassemble, analyze, reverse-engineer, alter, modify, translate or copy Product, whether in whole or in part.
- Product shall not be used for or incorporated into any products or systems whose manufacture, use, or sale is prohibited under any
  applicable laws or regulations.
- The information contained herein is presented only as guidance for Product use. No responsibility is assumed by TOSHIBA for any infringement of patents or any other intellectual property rights of third parties that may result from the use of Product. No license to any intellectual property right is granted by this document, whether express or implied, by estoppel or otherwise.
- ABSENT A WRITTEN SIGNED AGREEMENT, EXCEPT AS PROVIDED IN THE RELEVANT TERMS AND CONDITIONS OF SALE
  FOR PRODUCT, AND TO THE MAXIMUM EXTENT ALLOWABLE BY LAW, TOSHIBA (1) ASSUMES NO LIABILITY
  WHATSOEVER, INCLUDING WITHOUT LIMITATION, INDIRECT, CONSEQUENTIAL, SPECIAL, OR INCIDENTAL DAMAGES OR
  LOSS, INCLUDING WITHOUT LIMITATION, LOSS OF PROFITS, LOSS OF OPPORTUNITIES, BUSINESS INTERRUPTION AND
  LOSS OF DATA, AND (2) DISCLAIMS ANY AND ALL EXPRESS OR IMPLIED WARRANTIES AND CONDITIONS RELATED TO
  SALE, USE OF PRODUCT, OR INFORMATION, INCLUDING WARRANTIES OR CONDITIONS OF MERCHANTABILITY, FITNESS
  FOR A PARTICULAR PURPOSE, ACCURACY OF INFORMATION, OR NONINFRINGEMENT.
- GaAs (Gallium Arsenide) is used in Product. GaAs is harmful to humans if consumed or absorbed, whether in the form of dust or vapor.
   Handle with care and do not break, cut, crush, grind, dissolve chemically or otherwise expose GaAs in Product.
- Do not use or otherwise make available Product or related software or technology for any military purposes, including without limitation, for the design, development, use, stockpiling or manufacturing of nuclear, chemical, or biological weapons or missile technology products (mass destruction weapons). Product and related software and technology may be controlled under the applicable export laws and regulations including, without limitation, the Japanese Foreign Exchange and Foreign Trade Law and the U.S. Export Administration Regulations. Export and re-export of Product or related software or technology are strictly prohibited except in compliance with all applicable export laws and regulations.
- Please contact your TOSHIBA sales representative for details as to environmental matters such as the RoHS compatibility of Product.
   Please use Product in compliance with all applicable laws and regulations that regulate the inclusion or use of controlled substances, including without limitation, the EU RoHS Directive TOSHIBA ASSUMES NO LIABILITY FOR DAMAGES OR LOSSES
   OCCURRING AS A RESULT OF NONCOMPLIANCE WITH APPLICABLE LAWS AND REGULATIONS.

# **Mouser Electronics**

**Authorized Distributor** 

Click to View Pricing, Inventory, Delivery & Lifecycle Information:

## Toshiba:

TLP620(GR,F) TLP620(D4GB-T1,F,T TLP620(F,T) TLP620(GB,F,T) TLP620(D4-GB,F,T)